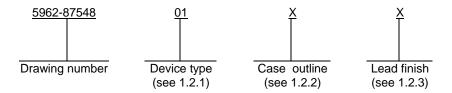
								F	REVISI	ONS													
LTR						DESCR	RIPTIO	N					[DATE (YR-MO-D	DA)		APPR	OVED				
А	Chai	nges ir	accor	dance	with N	OR 596	62-R02	0-99.	- LTG					99-0	1-28		М	Monica L. Poelking					
В	Chai	nges ir	accor	dance	with N	OR 596	62-R00	9-00.	- TVN					00-0	1-12		Mo	onica L	. Poelki	ing			
С	Dele wave	te I _{OH} a	and I _{OL} or data	in foot a floatir	/ _{IN} and tnote <u>3</u> / ng test	in tabl	e I. Ad	dd test	circuit	and ou	tput			00-0	7-14		Mo	onica L	. Poelki	ing			
D	Upda	ate boi	lerplate	e to MI	L-PRF-	-38535	require	ements	s CF	-S				05-0	9-07		Т	homas	M. Hes	SS			
THE ORIGIN	NAL FII	RST S	SHEET	OF T	HIS DF	RAWIN	IG HA	S BEE	:N REI	PLACE	ĒD.												
SHEET		_							_														
REV SHEET	D 15	D 16	D 17	D 18	D 19	D 20	D 21	D 22	D 23														
REV STATUS		10	17	RE\		20	D	D	D	D	D	D	D	D	D	D	D	D	D	D			
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DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE			1								i —			1			NOLITHIC SILICON						
		DEFEN	NSE	REV	ISION	LEVEL				SIZE			E COE 726			59	962-	875	48	ON			

1. SCOPE

- 1.1 <u>Scope</u>. This drawing describes device requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A.
 - 1.2 Part or Identifying Number (PIN). The complete PIN is as shown in the following example:



1.2.1 <u>Device type(s)</u>. The device type(s) identify the circuit function as follows:

Device type	Generic number	<u>Circuit function</u>		
01	8251A	Programmable communication interface		
02	8251A	Programmable communication interface		

1.2.2 <u>Case outline(s)</u>. The case outline(s) are as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
Χ	GDIP1-T28 or CDIP2-T28	28	Dual-in-line
3	CQCC1-N28	28	Square leadless chip carrier

- 1.2.3 Lead finish. The lead finish is as specified in MIL-PRF-38535, appendix A.
- 1.3 Absolute maximum ratings.

Supply voltage range	-0.5 V dc to +7 V dc
Input voltage range	-0.5 V dc to +7 V dc
V _{CC} with respect to V _{SS}	
All signal voltages with respect to V _{SS}	-0.5 V dc to +7 V dc
Maximum power dissipation (P _D)	1.0 W
Storage temperature range	
Lead temperature (soldering, 5 seconds)	+270°C
Thermal resistance, junction-to-case (θ_{JC})	
Junction temperature (T _J)	

1.4 Recommended operating conditions.

Supply voltage range (V _{CC}):	
Device type 01	+4.5 V dc to +5.5 V dc
Device type 02	+4.75 V dc to +5.25 V dc
Minimum low level input voltage (V _{IL})	-0.5 V dc
Minimum high level input voltage (V _{IH})	+2.2 V dc
Maximum low level input voltage (V _{II})	+0.8 V dc
Maximum high level input voltage (VIH)	V_{CC}
Case operating temperature range (T _C)	-55°C to +125°C

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2. APPLICABLE DOCUMENTS

2.1 <u>Government specification, standards, and handbooks</u>. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.

MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.
MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at http://assist.daps.dla.mil/quicksearch/ or http:

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

- 3.1 <u>Item requirements</u>. The individual item requirements shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein. Product built to this drawing that is produced by a Qualified Manufacturer Listing (QML) certified and qualified manufacturer or a manufacturer who has been granted transitional certification to MIL-PRF-38535 may be processed as QML product in accordance with the manufacturers approved program plan and qualifying activity approval in accordance with MIL-PRF-38535. This QML flow as documented in the Quality Management (QM) plan may make modifications to the requirements herein. These modifications shall not affect form, fit, or function of the device. These modifications shall not affect the PIN as described herein. A "Q" or "QML" certification mark in accordance with MIL-PRF-38535 is required to identify when the QML flow option is used. This drawing has been modified to allow the manufacturer to use the alternate die/fabrication requirements of paragraph A.3.2.2 of MIL-PRF-38535 or other alternative approved by the Qualifying Activity.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535, appendix A and herein.
 - 3.2.1 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.
 - 3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.3 True table. The true table shall be as specified on figure 2.
 - 3.2.4 Block diagram. The block diagram shall be as specified on figure 3.
 - 3.2.5 Switching waveforms and test circuit. The switching waveforms and test circuit shall be as specified on figure 4.
- 3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full case operating temperature range.
- 3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.

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- 3.5 <u>Marking</u>. Marking shall be in accordance with MIL-PRF-38535, appendix A. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device.
- 3.5.1 <u>Certification/compliance mark</u>. A compliance indicator "C" shall be marked on all non-JAN devices built in compliance to MIL-PRF-38535, appendix A. The compliance indicator "C" shall be replaced with a "Q" or "QML" certification mark in accordance with MIL-PRF-38535 to identify when the QML flow option is used. For product built in accordance with A.3.2.2 of MIL-PRF-38535, or as modified in the manufacturer's QM plan, the "QD" certification mark shall be used in place of the "Q" or "QML" certification mark.
- 3.6 <u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-PRF-38535, appendix A and the requirements herein.
- 3.7 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.
 - 3.8 Notification of change. Notification of change to DSCC-VA shall be required for any change that affects this drawing.
- 3.9 <u>Verification and review</u>. DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

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		TABLE I. Electrical performance char	racteristics				
Test	Symbol	Conditions $-55^{\circ}\text{C} \le T_{\text{C}} \le +125^{\circ}\text{C}$	Device type	Group A subgroups	Lin	nits	Unit
		V_{CC} = 5 V ±10% for device type 01 V_{CC} = 5 V ±5% for device type 02 unless otherwise specified			Min	Max	
Input low voltage	V _{IL}		All	1, 2, 3		0.8	V
Input high voltage	V _{IH}		All	1, 2, 3	2.2		V
Low level output voltage	V _{OL}	I _{OL} = 2.2 mA	All	1, 2, 3		0.45	V
High level output voltage	V _{OH}	I _{OH} = -400 μA	All	1, 2, 3	2.4		V
Input leakage current	I _{IL}	$V_{IN} = V_{CC}$ max and 0.45 V	All	1, 2, 3		±10 <u>1</u> /	μА
Output float leakage current	I _{OFL}	$V_{OUT} = V_{CC}$ max and 0.45 V	All	1, 2, 3		±10 <u>1</u> /	μА
Power supply current	I _{CC}	Outputs unloaded static 2/	All	1, 2, 3		120	mA
Input capacitance	C _{IN}	f _C = 1 MHz See 4.3.1d	All	4		10	pF
I/O capacitance	C _{I/O}	Unmeasured pins returned to GND See 4.3.1d		4		20	
Functional test		See 4.3.1c	All	7, 8			
		READ CYCLE					
Address stable before RD	t _{AR}	See figure 4 <u>3</u> / <u>4</u> / <u>5</u> /	All	9, 10, 11	0		ns
Address hold time to RD	t _{RA}	See figure 4 <u>3</u> / <u>4</u> / <u>5</u> /	All	9, 10, 11	0		ns
RD pulse width	t _{RR}	See figure 4 <u>3</u> / <u>4</u> /	All	9, 10, 11	250		ns
Data delay from RD	t _{RD}	See figure 4 <u>3</u> / <u>4</u> / <u>6</u> / <u>7</u> /	All	9, 10, 11		200	ns
RD to data floating	t _{DF}	See figure 4 3/ 4/	All	9, 10, 11	10 <u>1</u> /	250	ns
	_	WRITE CYCLE					
Address stable before WR	t _{AW}	See figure 4 <u>3</u> / <u>4</u> /	All	9, 10, 11	0		ns
Address hold time to WR	t _{WA}	See figure 4 <u>3</u> / <u>4</u> /	All	9, 10, 11	20		ns
WR pulse width	t _{WW}	See figure 4 <u>3</u> / <u>4</u> /	All	9, 10, 11	250		ns
Data setup for WR	t _{DW}	See figure 4 <u>3</u> / <u>4</u> /	All	9, 10, 11	150		ns

See footnotes at end of table.

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		+			+			
Test	Symbol		iditions Γ _C ≤ +125°C	Device type	Group A subgroups	Li	imits	Unit
		$V_{CC} = 5 \text{ V} \pm 10\%$ $V_{CC} = 5 \text{ V} \pm 5\% \text{ f}$	for device type 01 for device type 02 rwise specified			Min	Max	
		WRITE	CYCLE - Continue	ed				
Data hold for WR	t _{WD}	See figure 4 3/	<u>4</u> /	All	9, 10, 11	20		ns
Recover time between WR	t _{RV}	See figure 4 3/	<u>4/</u> <u>8</u> /	All	9, 10, 11	6 <u>1</u> /		t _{CY}
		0	THER TIMINGS					
Clock period <u>9</u> /	t _{CY}	See figure 4 3/	<u>4</u> / <u>10</u> / <u>11</u> /	All	9, 10, 11	320	1350	ns
Clock high pulse width	t _{HO}	See figure 4 3/	<u>4</u> /	All	9, 10, 11	140	t _{CY} - 90 <u>12</u> /	ns
Clock low pulse width	t _{LO}	See figure 4 3/	<u>4</u> /	All	9, 10, 11	90		ns
TxD delay from falling edge of TxC	t _{DTX}	See figure 4 3/	<u>4</u> /	All	9, 10, 11		1	μS
Transmitter input clock frequency	f _{TX}	1 x Baud rate	<u>3</u> / <u>4</u> /	All	9, 10, 11	<u>1</u> / dc	64	kH
		16 x Baud rate				<u>1</u> / dc	310	
		64 x Baud rate				<u>1</u> / dc	615	
Transmitter input clock	t _{TPW}	1 x Baud rate	See figure 4	All	9, 10, 11	12	<u> </u>	t _C
pulse width		16 x Baud rate	<u>3</u> / <u>4</u> /			1		
		64 x Baud rate				1		
Transmitter input clock pulse delay	t _{TPD}	1 x Baud rate	See figure 4 3/ 4/	All	9, 10, 11	15		t _C
puise delay		16 x Baud rate	<u> </u>		ļ	3		
		64 x Baud rate				3		
Receiver input clock frequency	f _{RX}	1 x Baud rate	<u>3</u> / <u>4</u> /	All	9, 10, 11	<u>1</u> / dc	64	k⊦
		16 x Baud rate				<u>1</u> / dc	310	
		64 x Baud rate				<u>1</u> / dc	615	
Receiver input clock	t _{RPW}	1 x Baud rate	See figure 4	All	9, 10, 11	12	T	t _C
pulse width		16 x Baud rate	<u>3</u> / <u>4</u> /			1		
		64 x Baud rate			'	1		

See footnotes at end of table.

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	TABLE I. <u>Electrical performance characteristics</u> - Continued.							
Test	Symbol	-55°C ≤ T	Conditions C -55°C \leq T _C \leq +125°C		Group A subgroups		nits	Unit
		$V_{CC} = 5 \text{ V} \pm 5\% \text{ f}$	for device type 01 for device type 02 wise specified			Min	Max	
	1	OTHER	TIMINGS - Continu	ed				
Receiver input clock	t _{RPD}	1 x Baud rate	See figure 4	All	9, 10, 11	15		t _{CY}
pulse delay		16 x Baud rate	<u>3</u> / <u>4</u> /			3		
		64 x Baud rate				3		
TxRDY delay from	t _{TxRDY}	See figure 4 3/	<u>4</u> / <u>13</u> /	01	9, 10, 11		12	t _{CY}
center of last bit				02			14	
TxRDY fall from leading edge of WR	t _{TxRDY} CLEAR	<u>3</u> / <u>4</u> / <u>13</u> /		All	9, 10, 11		400	ns
RxRDY delay from center of last bit	t _{RxRDY}	See figure 4 3/	<u>4</u> / <u>13</u> /	All	9, 10, 11		26	t _{CY}
RxRDY fall from leading edge of WR	t _{RXRDY} CLEAR	<u>3</u> / <u>4</u> / <u>13</u> /		All	9, 10, 11		400	ns
Internal SYNDET delay from rising edge of RxC	t _{IS}	See figure 4 3/	<u>4</u> / <u>13</u> /	All	9, 10, 11		26	t _{CY}
External SYNDET setup after rising edge of RxC	t _{ES}	See figure 4 3/	<u>4</u> / <u>13</u> /	All	9, 10, 11	16		t _{CY}
TxEMPTY delay from center of last bit	t _{TXEMPTY}	See figure 4 3/	<u>4</u> / <u>13</u> /	All	9, 10, 11		20	t _{CY}
Control delay from rising edge of WR	t _{WC}	See figure 4 3/	<u>4</u> / <u>13</u> /	All	9, 10, 11		8	t _{CY}
Control to RD setup time	t _{CR}	<u>3</u> / <u>4</u> / <u>13</u> /		All	9, 10, 11	20		t _{CY}

- 1/ Guaranteed if not tested.
- 2/ I_{CC} is measured in a static condition with outputs in the worst condition with all outputs unloaded.
- Test conditions: $V_{CC} = 5 \text{ V} \pm 10\%$ for device type 01. $V_{CC} = 5 \text{ V} \pm 5\%$ for device type 02. (See figure 4) $V_{IL} = 0.45 \text{ V}$ $V_{IH} = 2.4 \text{ V}$

 $\begin{array}{ll} V_{IL} = 0.45 \; V & V_{IH} = 2.4 \; V \\ V_{OL} = 0.8 \; V & V_{OH} = 2.0 \; V \end{array}$

- 4/ Clock rise and fall times are controlled by the test equipment. Measurement of typical generated signal are $t_R = t_F = 5$ ns.
- 5/ Chip Select (\overline{CS}) and Command/Data (\overline{CD}) are considered as addresses.
- 6/ Test condition: $C_L = 100 \text{ pF}$ (see figure 4).
- 7/ Assumes that address is valid before $\overline{RD} \downarrow$.
- 8/ This recovery time is for after a mode instruction only. Write data is allowed only when TxRDY = 1. Recovery time between writes for asynchronous mode is 8 t_{CY} and for synchronous mode is 16 t_{CY} .
- 9/ Due to test equipment limitations, actual tested values may differ from those specified but specified values are guaranteed.
- 10/ The TxC and RxC frequencies have the following limitations with respect to CLK: For 1 x Baud rate, f_{TX} or $f_{RX} \le 1/(30 \ t_{CY})$. For 16 x and 64 x Baud rate, f_{TX} or $f_{RX} \le 1/(4.5 \ t_{CY})$.
- 11/ Reset pulse width = 6 t_{CY} minimum; system clock must be running during reset.
- 12/ Limit may be guaranteed by indirect testing if not tested directly.
- 13/ Status update can have a maximum delay of 28 clock periods from the event affecting the status.

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Device type	All				
Case outlines	X and 3				
Terminal number	Terminal symbol	Terminal number	Terminal symbol		
1	D_2	15	TxRDY		
2	D_3	16	SYNDET/BD		
3	RxD	17	CTS		
4	GND	18	TxEMPTY		
5	D_4	19	TxD		
6	D_5	20	CLK		
7	D_6	21	RESET		
8	D_7	22	DSR		
9	TxC	23	RTS		
10	WR	24	DTR		
11	CS	25	RxC		
12	C/D	26	V _{cc}		
13	RD	27	D ₀		
14	RxRDY	28	D ₁		

FIGURE 1. <u>Terminal connections</u>.

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READ/WRITE LOGIC FUNCTION

C/D	RD	WR	CS	
0	0	1	0	DEVICE DATA → DATA BUS
0	1	0	0	DATA BUS → DEVICE DATA
1	0	1	0	$STATUS \rightarrow DATA BUS$
1	1	0	0	DATA BUS → CONTROL
Х	1	1	0	DATA BUS → THREE-STATE
Х	Х	Х	1	DATA BUS \rightarrow THREE-STATE

FIGURE 2. Truth table.

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Block diagram showing data bus buffer and read/write logic functions

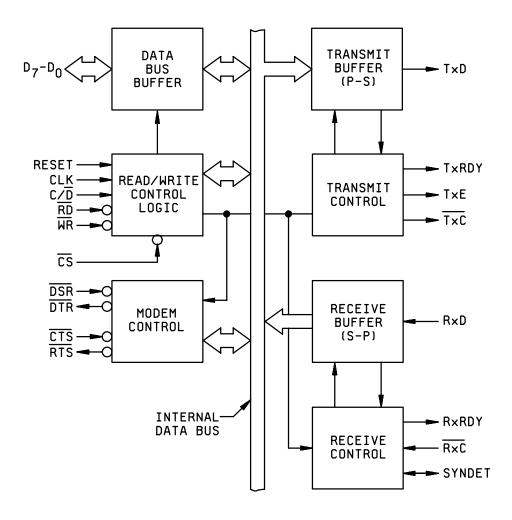
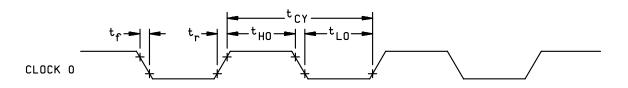


FIGURE 3. Block diagram.

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SYSTEM CLOCK INPUT



TRANSMITTER CLOCK AND DATA

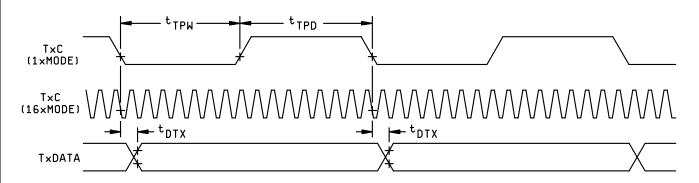


FIGURE 4. Switching waveforms and test circuit.

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RECEIVER CLOCK AND DATA

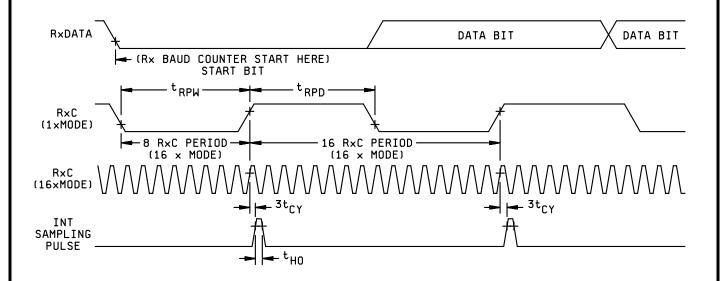


FIGURE 4. Switching waveforms and test circuit - Continued.

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DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
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WRITE DATA CYCLE(CPU -- USART)

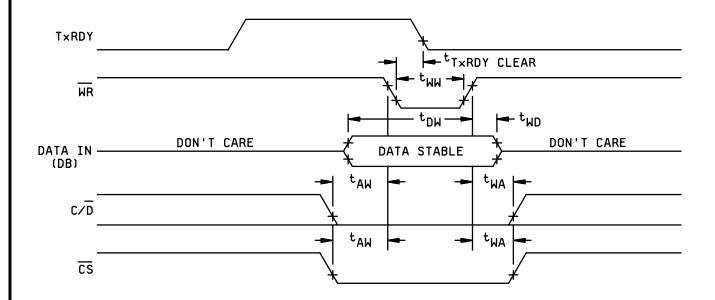


FIGURE 4. Switching waveforms and test circuit - Continued.

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DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43218-3990		D	13

READ DATA CYCLE (CPU - USART)

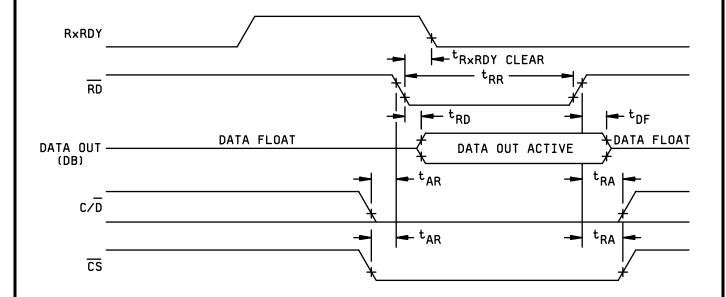


FIGURE 4. Switching waveforms and test circuit - Continued.

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WRITE CONTROL OR OUTPUT PORT CYCLE(CPU → USART)

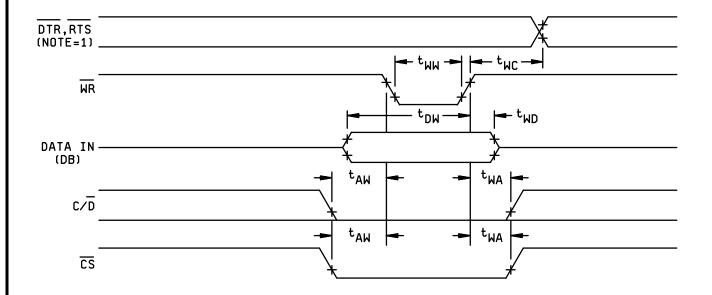
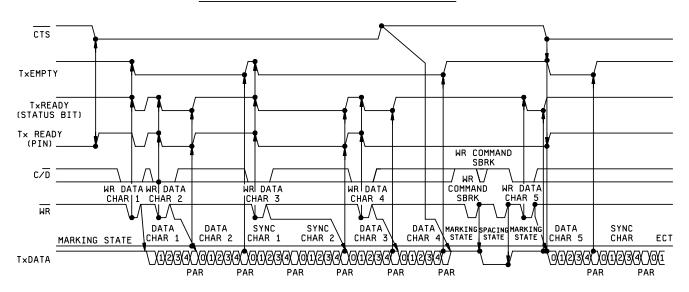


FIGURE 4. Switching waveforms and test circuit - Continued.

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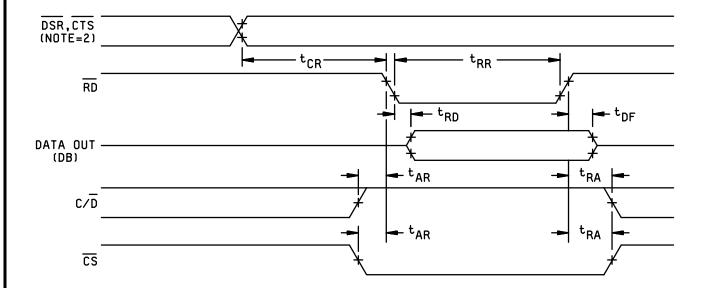
TRANSMITTER CONTROL AND FLAG TIMING(SYNC MODE)



EXAMPLE FORMAT - 5 BIT CHARACTER WITH PARITY 2 SYNC CHARACTER.

FIGURE 4. Switching waveforms and test circuit - Continued.

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NOTES:

- t_{WC} includes the response timing of a control byte.
 t_{CR} includes the effect of CTS on the TxENBL circuitry.

FIGURE 4. Switching waveforms and test circuit - Continued.

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TRANSMITTER CONTROL AND FLAG TIMING (ASYNC MODE)

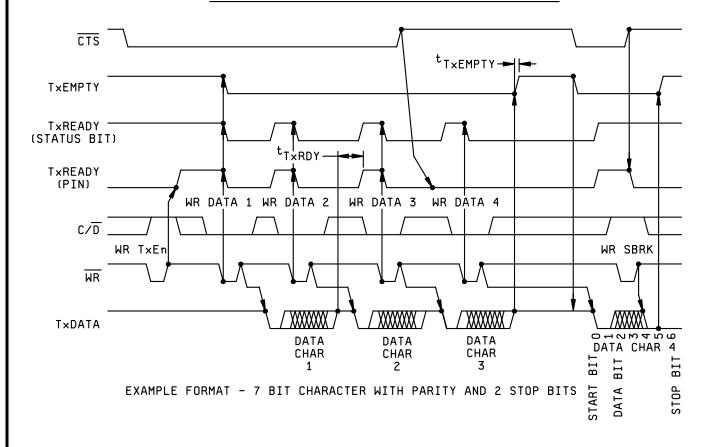
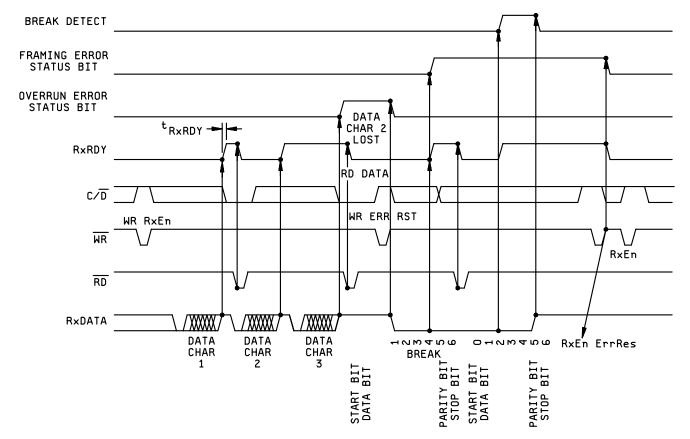


FIGURE 4. Switching waveforms and test circuit - Continued.

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RECEIVER CONTROL AND FLAG TIMING (ASYNC MODE)

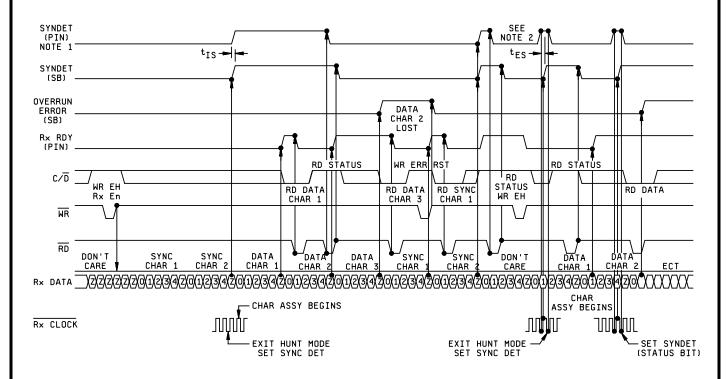


EXAMPLE FORMAT - 7 BIT CHARACTER WITH PARITY 2 AND STOP BITS

FIGURE 4. Switching waveforms and test circuit - Continued.

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RECEIVER CONTROL AND FLAG TIMING(SYNC MODE)



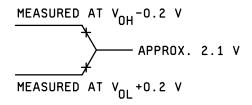
NOTES:

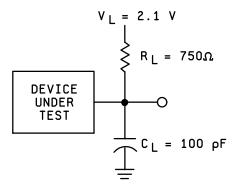
- 1. Internal sync, 2 sync characters, 5 bits with parity.
- 2. External sync, 5 bits with parity.

FIGURE 4. Switching waveforms and test circuit - Continued.

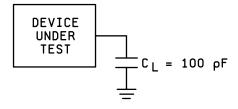
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OUTPUT WAVEFORM AND TEST CIRCUIT FOR DATA FLOATING (tDF)





$\underline{\mathsf{INPUT/OUTPUT}}\; \mathsf{WAVEFORM}\; \mathsf{AND}\; \mathsf{TEST}\; \mathsf{CIRCUIT}\; (\mathsf{EXCEPT}\; \mathsf{DATA}\; \mathsf{FLOATING}\; (t_{\mathsf{DF}})$



INPUT/OUTPUT WAVEFORM

NOTES:

- 1. AC testing inputs are driven at 2.4 V for a logic "1" and 0.45 V for a logic "0".
- 2. Timing measurements are made at 2.0 V for a logic "1" and 0.8 V for a logic "0".

FIGURE 4. Switching waveforms and test circuit - Continued.

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4. VERIFICATION

- 4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.
- 4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
 - (2) $T_A = +125^{\circ}C$, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)
Interim electrical parameters (method 5004)	
Final electrical test parameters (method 5004)	1*, 2, 3, 7, 8, 9, 10, 11
Group A test requirements (method 5005)	1, 2, 3, 7, 8, 9, 10, 11
Groups C and D end-point electrical parameters (method 5005)	1, 2, 3 or 2, 8 (hot), 10
Additional electrical subgroups for group C periodic inspections	

^{*} PDA applies to subgroup 1.

4.3 <u>Quality conformance inspection</u>. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

4.3.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. Subgroups 5 and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.
- c. Subgroups 7 and 8 shall include verification of the truth table.
- d. Subgroup 4 (C_{IN} and C_{I/O} measurements) shall be measured initially and after process or design changes which may affect capacitance. A minimum sample size of 5 devices with zero failures shall be required.

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4.3.2 Groups C and D inspections.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. Steady-state life test conditions, method 1005 of MIL-STD-883.
 - (1) Test condition C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.
 - (2) $T_A = +125^{\circ}C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535, appendix A.

6. NOTES

- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.
- 6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.
- 6.4 <u>Record of users</u>. Military and industrial users shall inform Defense Supply Center Columbus (DSCC) when a system application requires configuration control and the applicable SMD. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0544.
- 6.5 <u>Comments</u>. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0547.
- 6.6 <u>Approved sources of supply</u>. Approved sources of supply are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.

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STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 05-09-07

Approved sources of supply for SMD 5962-87548 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and/or QML-38535 during the next revision. MIL-HDBK-103 and/or QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and/or QML-38535. DSCC maintains an online database of all current sources of supply at http://www.dscc.dla.mil/Programs/Smcr/.

Standard microcircuit drawing PIN <u>1</u> /	Vendor CAGE number	Vendor similar PIN <u>2</u> /
5962-8754801XA	<u>3</u> /	8251A
5962-8754802XA	3V146	MD8251A/BXA
5962-87548023A	3V146	MR8251A/B3A

- The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.
- 2/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.
- 3/ Not available from an approved source of supply.

 Vendor CAGE number
 Vendor name and address

 3V146
 Rochester Electronics 10 Malcolm Hovt Drive

Newburyport, MA 01950

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in the information bulletin.